

Attorney's Docket No.: 07977-052001/US3053

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Hisashi Ohtani, et al      Art Unit : 1765  
Serial No.: 08/690,747                      Examiner : Robert Kunemund  
Filed : August 1, 1996                      Confirmation No. : 1369  
Title : METHOD FOR MANUFACTURING SEMICONDUCTOR DEVICE

Commissioner for Patents  
Washington, D.C. 20231

AMENDMENT

Sir:

In response to the Official Action dated June 26, 2002,  
Paper No. 29, in the above-referenced application, kindly amend  
the above-identified application as follows.

In the Claims:

Please amend the claims as follows.

55. A method for manufacturing a semiconductor device  
comprising:  
forming a semiconductor film comprising silicon over a  
substrate;  
providing said semiconductor film with a crystallization  
promoting material;

## CERTIFICATE OF TRANSMISSION BY FACSIMILE

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October 28, 2002

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